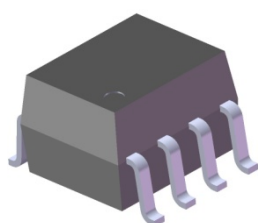


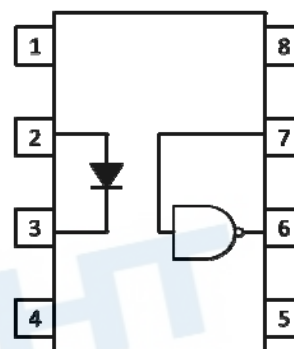
### 8 PIN SOP HIGH SPEED 10MBit/s LOGIC GATE PHOTOCOUPLER EL06XX Series



#### Features

- Compliance Halogen Free  
(Br <900 ppm , Cl <900 ppm , Br+Cl < 1500 ppm)
- High speed 10Mbit/s
- 10kV/μs minimum common mode transient immunity  
at VCM= 1KV (EL0611)
- Guaranteed performance from -40 to 85°C
- Wide operating temperature range of -40°C to 100°C
- Logic gate output
- High isolation voltage between input  
and output (Viso=3750 V rms )
- Compliance with EU REACH
- Pb free and RoHS compliant.
- UL and cUL approved (No. E214129)
- VDE approved (No. 40028116)
- SEMKO approved
- NEMKO approved
- DEMKO approved
- FIMKO approved

#### Schematic



A 0.1μF bypass capacitor must be connected between pins 8 and 5 \*

#### Pin Configuration

- 1, No Connection
- 2, Anode
- 3, Cathode
- 4, No Connection
- 5, Gnd
- 6, V<sub>out</sub>
- 7, V<sub>E</sub>
- 8, V<sub>CC</sub>

#### Description

The EL0600, EL0601 and EL0611 devices each consists of an infrared emitting diode optically coupled to a high speed integrated photo detector logic gate with a strobable output.

The devices are packaged in an 8-pin small outline package which conforms to the standard SO8 footprint.

#### Applications

- Ground loop elimination
- LSTTL to TTL, LSTTL or 5 volt CMOS
- Line receiver, data transmission
- Data multiplexing
- Switching power supplies
- Pulse transformer replacement
- Computer peripheral interface
- High speed logic ground isolation

#### Truth Table (Positive Logic)

Input	Enable	Output
H	H	L
L	H	H
H	L	H
L	L	H
H	NC	L
L	NC	H

## Absolute Maximum Ratings (Ta=25°C)

	Parameter	Symbol	Rating	Unit
Input	Forward current	I <sub>F</sub>	20	mA
	Enable input voltage Not exceed V <sub>CC</sub> by more than 500mV	V <sub>E</sub>	5.5	V
	Reverse voltage	V <sub>R</sub>	5	V
	Power dissipation	P <sub>D</sub>	40	mW
Output	Power dissipation	P <sub>C</sub>	85	mW
	Enable input current	I <sub>E</sub>	5	mA
	Output current	I <sub>O</sub>	50	mA
	Output voltage	V <sub>O</sub>	7.0	V
	Output Power Dissipation	P <sub>O</sub>	100	mW
	Isolation voltage <sup>*1</sup>	V <sub>ISO</sub>	3750	V rms
	Operating temperature	T <sub>OPR</sub>	-40 ~ +100	°C
	Storage temperature	T <sub>STG</sub>	-55 ~ +125	°C
	Soldering temperature <sup>*2</sup>	T <sub>SOL</sub>	260	°C

### Notes:

\*1 AC for 1 minute, R.H.= 40 ~ 60% R.H. In this test, pins 1, 2, 3 & 4 are shorted together, and pins 5, 6, 7 & 8 are shorted together.

\*2 For 10 seconds.

## Electrical Characteristics (Ta=-40 to 85°C unless specified otherwise)

### Input

Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition
Forward voltage	$V_F$	-	1.4	1.8	V	$I_F = 10\text{mA}$
Reverse voltage	$V_R$	5.0	-	-	V	$I_R = 10\mu\text{A}$
Temperature coefficient of forward voltage	$\Delta V_F / \Delta T_A$	-	-1.8	-	mV/°C	$I_F = 10\text{mA}$
Input capacitance	$C_{IN}$	-	60	-	pF	$V_F = 0, f = 1\text{MHz}$

Note: Reverse Voltage(VR) Condition is applied to IR test only The device is not designed for reverse operation

### Output

Parameter	Symbol	Min	Typ.	Max.	Unit	Condition
High level supply current	$I_{CCH}$	-	-	10	mA	$I_F = 0\text{mA}, V_E = 0.5\text{V}, V_{CC} = 5.5\text{V}$
Low level supply current	$I_{CCL}$	-	-	13	mA	$I_F = 10\text{mA}, V_E = 0.5\text{V}, V_{CC} = 5.5\text{V}$
High level enable current	$I_{EH}$	-	-	-1.6	mA	$V_E = 2.0\text{V}, V_{CC} = 5.5\text{V}$
Low level enable current	$I_{EL}$	-	-	-1.6	mA	$V_E = 0.5\text{V}, V_{CC} = 5.5\text{V}$
High level enable voltage	$V_{EH}$	2.0	-	-	V	$I_F = 10\text{mA}, V_{CC} = 5.5\text{V}$
Low level enable voltage*4	$V_{EL}$	-	-	0.8	V	$I_F = 10\text{mA}, V_{CC} = 5.5\text{V}$

## Transfer Characteristics (Ta=-40 to 85°C unless specified otherwise)

Parameter	Symbol	Min	Typ.	Max.	Unit	Condition
HIGH Level Output Current	$I_{OH}$	-	-	100	uA	$V_{CC} = 5.5\text{V}, V_O = 5.5\text{V}, I_F = 250\mu\text{A}, V_E = 2.0\text{V}$
LOW Level Output Current	$V_{OL}$	-	-	0.6	V	$V_{CC} = 5.5\text{V}, I_F = 5\text{mA}, V_E = 2.0\text{V}, I_{CL} = 13\text{mA}$
Input Threshold Current	$I_{FT}$	-	-	5	mA	$V_{CC} = 5.5\text{V}, V_O = 0.6\text{V}, V_E = 2.0\text{V}, I_{OL} = 13\text{mA}$

**Switching Characteristics ( $T_a=-40$  to  $85^{\circ}\text{C}$ ,  $V_{CC}=5\text{V}$ ,  $I_F=7.5\text{mA}$  unless specified otherwise)**

Parameter	Symbol	Min	Typ.	Max.	Unit	Condition
Propagation delay time to output High level* <sup>5</sup> (Fig.12)	$T_{PHL}$	-	35	75	ns	$C_L = 15\text{pF}$ , $R_L=350\Omega$ , $T_A=25^{\circ}\text{C}$
Propagation delay time to output Low level* <sup>6</sup> (Fig.12)	$T_{PLH}$	-	45	75	ns	$C_L = 15\text{pF}$ , $R_L=350\Omega$ , $T_A=25^{\circ}\text{C}$
Pulse width distortion	$ T_{phl} - T_{plh} $	-	10	35	ns	$C_L = 15\text{pF}$ , $R_L=350\Omega$
Output rise time* <sup>7</sup> (Fig.12)	$t_r$	-	30	40	ns	$C_L = 15\text{pF}$ , $R_L=350\Omega$
Output fall time* <sup>8</sup> (Fig.12)	$t_f$	-	10	20	ns	$C_L = 15\text{pF}$ , $R_L=350\Omega$

**Switching Characteristics ( $T_a=-40$  to  $85^{\circ}\text{C}$ ,  $V_{CC}=5\text{V}$ ,  $I_F=7.5\text{mA}$  unless specified otherwise)**

Parameter	Symbol	Min	Typ.	Max.	Unit	Condition
Enable Propagation Delay Time to Output High Level* <sup>9</sup> (Fig.13)	$t_{ELH}$	-	30	40	ns	$I_F = 7.5\text{mA}$ , $V_{EH}=3\text{V}$ , $C_L = 15\text{pF}$ , $R_L=350\Omega$
Enable Propagation Delay Time to Output Low Level* <sup>10</sup> (Fig.13)	$t_{EHL}$	-	20	30	ns	$I_F = 7.5\text{mA}$ , $V_{EH}=3\text{V}$ , $C_L = 15\text{pF}$ , $R_L=350\Omega$
Common Mode Transient Immunity at Logic High * <sup>11</sup>	EL0600	-	-	-	V/ $\mu\text{S}$	$I_F = 7.5\text{mA}$ , $V_{OH}=2.0\text{V}$ , $R_L=350\Omega$ , $T_A=25^{\circ}\text{C}$ $V_{CM}=10\text{Vp-p}$ (Fig.14)
	EL0601	5,000	-	-		$I_F = 7.5\text{mA}$ , $V_{OH}=2.0\text{V}$ , $R_L=350\Omega$ , $T_A=25^{\circ}\text{C}$ $V_{CM}=50\text{Vp-p}$ (Fig.14)
	EL0611	10,000	-	-		$I_F = 7.5\text{mA}$ , $V_{OH}=2.0\text{V}$ , $R_L=350\Omega$ , $T_A=25^{\circ}\text{C}$ $V_{CM}=400\text{Vp-p}$ (Fig.14)
	EL0611	15,000	-	-		$I_F = 7.5\text{mA}$ , $V_{OH}=2.0\text{V}$ , $R_L=350\Omega$ , $T_A=25^{\circ}\text{C}$ $V_{CM}=400\text{Vp-p}$ (Fig.15)
	EL0600	-	-	-		$I_F = 0\text{mA}$ , $V_{OL}=0.8\text{V}$ , $R_L=350\Omega$ , $T_A=25^{\circ}\text{C}$ $V_{CM}=10\text{Vp-p}$ (Fig.14)
Common Mode Transient Immunity at Logic Low * <sup>12</sup>	EL0601	5,000	-	-	V/ $\mu\text{S}$	$I_F = 0\text{mA}$ , $V_{OL}=0.8\text{V}$ , $R_L=350\Omega$ , $T_A=25^{\circ}\text{C}$ $V_{CM}=50\text{Vp-p}$ (Fig.14)
	EL0611	10,000	-	-		$I_F = 0\text{mA}$ , $V_{OL}=0.8\text{V}$ , $R_L=350\Omega$ , $T_A=25^{\circ}\text{C}$ $V_{CM}=400\text{Vp-p}$ (Fig.14)
	EL0611	15,000	-	-		$I_F = 7.5\text{mA}$ , $V_{OL}=0.8\text{V}$ , $R_L=350\Omega$ , $T_A=25^{\circ}\text{C}$ $V_{CM}=400\text{Vp-p}$ (Fig.15)
	EL0600	-	-	-		$I_F = 0\text{mA}$ , $V_{OL}=0.8\text{V}$ , $R_L=350\Omega$ , $T_A=25^{\circ}\text{C}$ $V_{CM}=10\text{Vp-p}$ (Fig.14)

## Typical Electro-Optical Characteristics Curves

Figure 1. Forward Current vs Forward Voltage

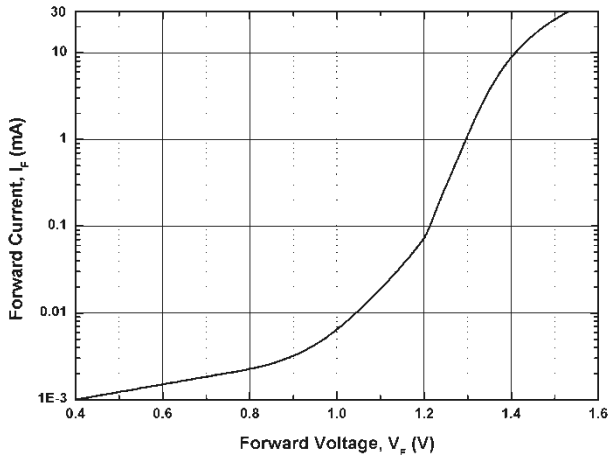


Figure 2. Low Level Output Voltage vs Ambient Temperature

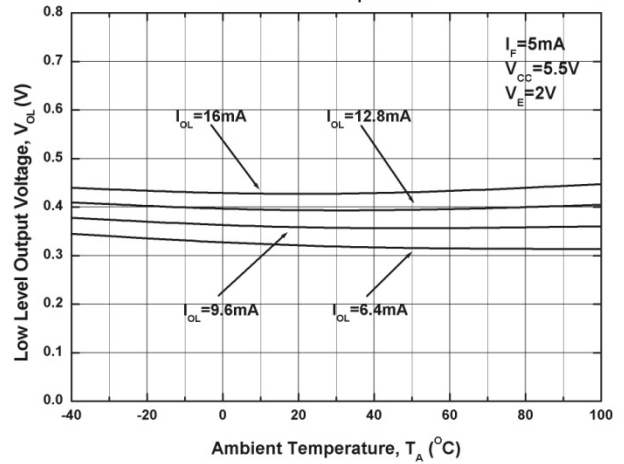


Figure 3. Low Level Output Current vs Ambient Temperature

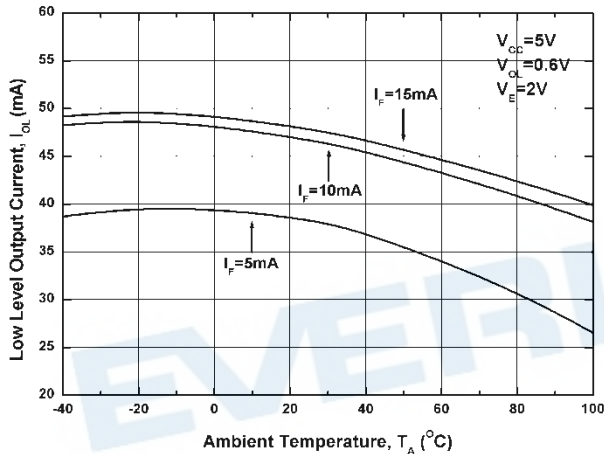


Figure 4. Input Threshold Current vs Ambient Temperature

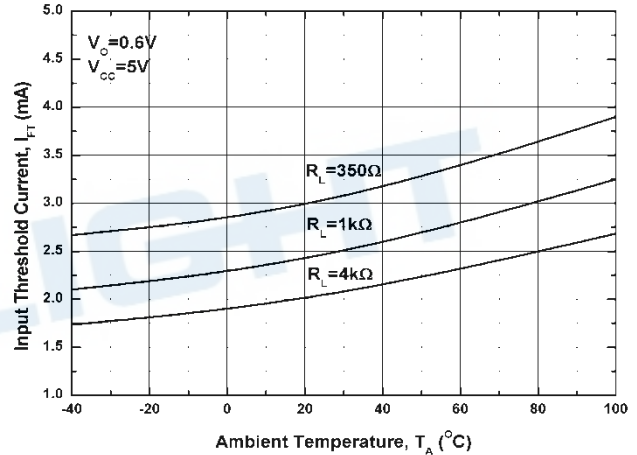


Figure 5. Input Current vs Output Voltage

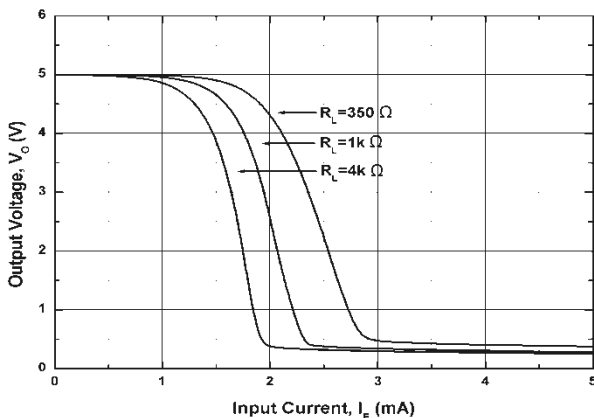


Figure 6. High Level Output Current vs Ambient Temperature

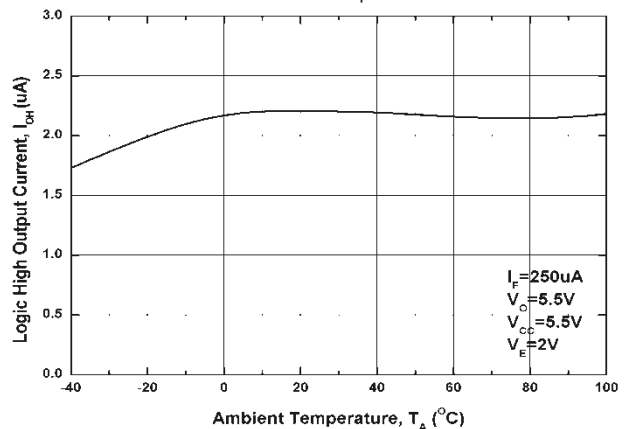


Figure 7. Propagation Delay vs. Forward Current

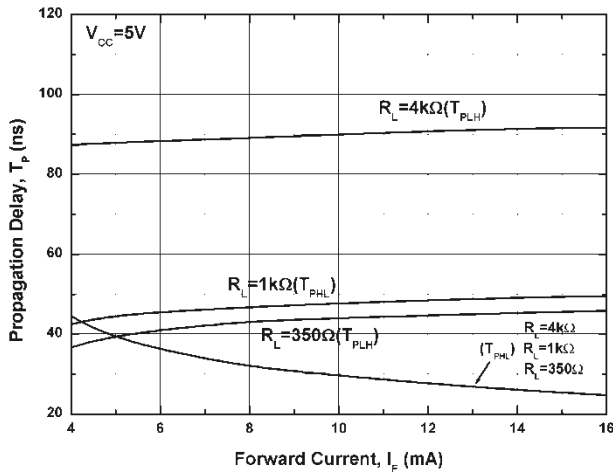


Figure 8. Propagation Delay vs. Temperature

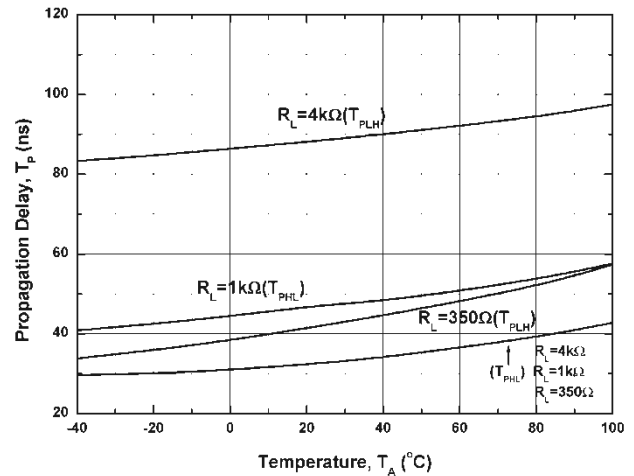


Figure 9. Pulse Width Distortion vs. Temperature

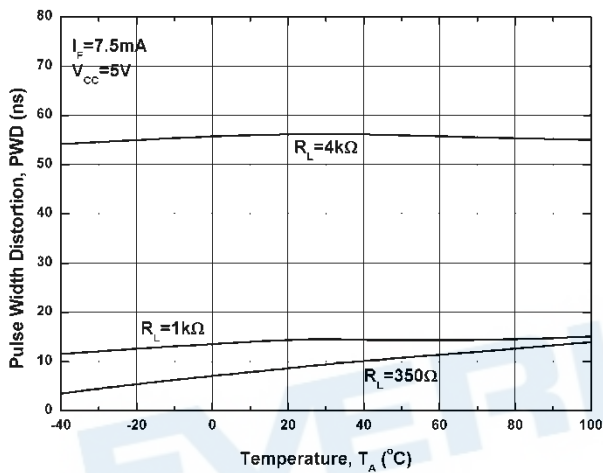


Figure 10. Rise and Fall Time vs. Temperature

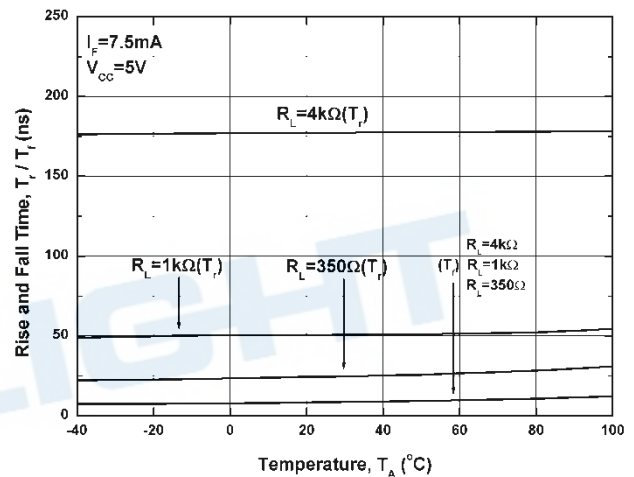
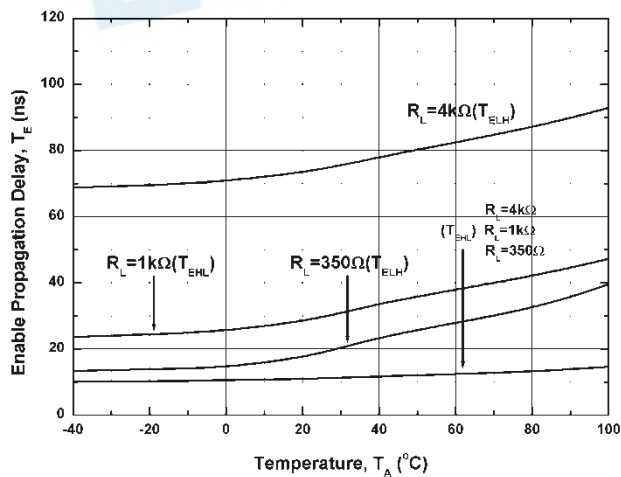


Figure 11. Enable Propagation Delay vs. Temperature



Note: The graphs shown in this datasheet are representing typical data only and do not show guaranteed values

Fig. 12 Test circuit and waveforms for  $t_{PHL}$ ,  $t_{PLH}$ ,  $t_r$ , and  $t_f$

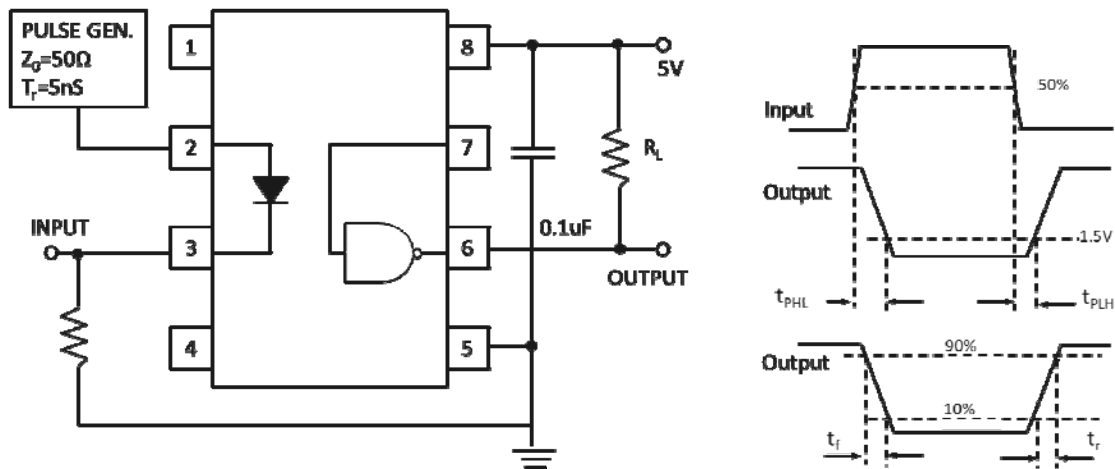


Fig. 13 Test circuit and waveform for  $t_{EHL}$  and  $t_{ELH}$

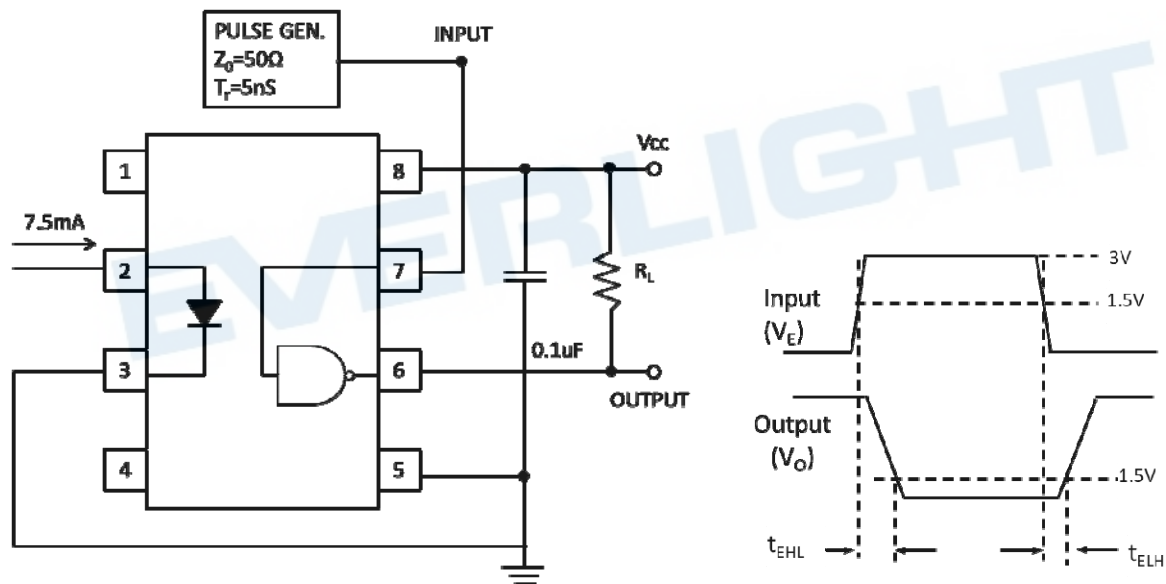


Fig. 14 Test circuit Common mode Transient Immunity

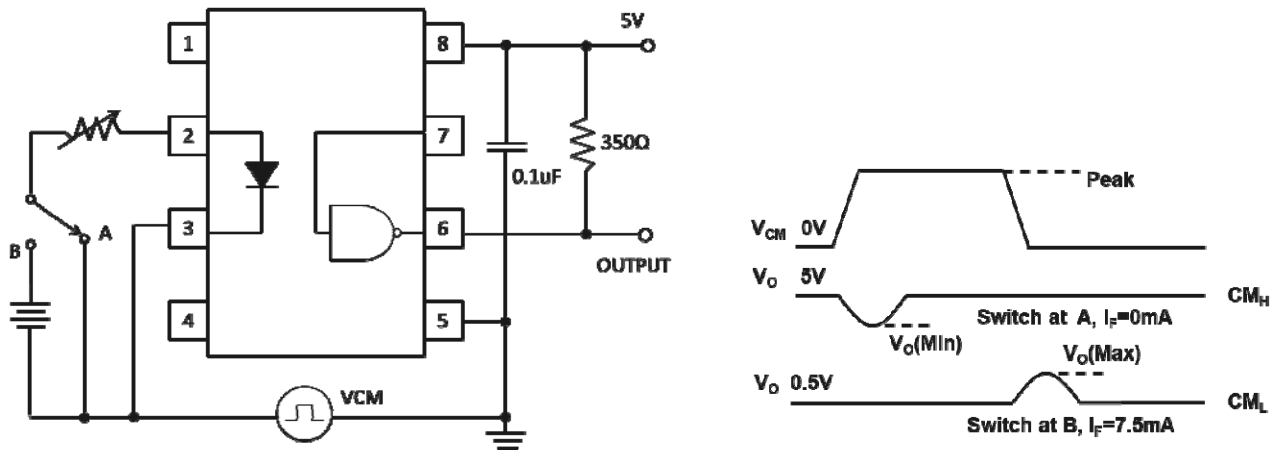
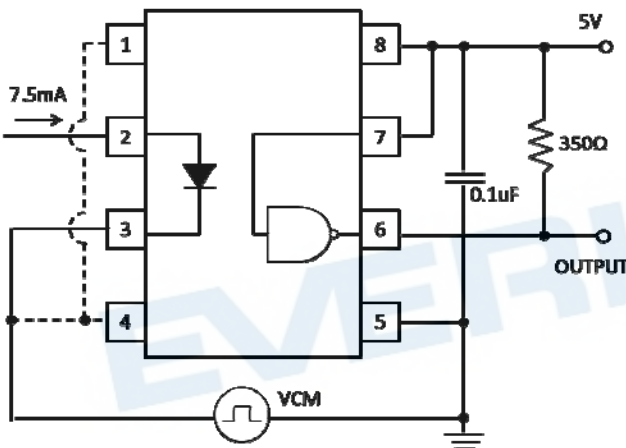


Fig. 15 Recommended drive circuit for EL0611 families for high-CMR



#### Notes

- \*3. The  $V_{CC}$  supply must be bypassed by a  $0.1\mu F$  capacitor or larger. This can be either a ceramic or solid tantalum capacitor with good high frequency characteristic and should be connected as close as possible to the package  $V_{CC}$  and GND pins
- \*4. Enable Input – No pull up resistor required as the device has an internal pull up resistor.
- \*5.  $t_{PLH}$  – Propagation delay is measured from the 3.75mA level on the HIGH to LOW transition of the input current pulse to the 1.5 V level on the LOW to HIGH transition of the output voltage pulse.
- \*6.  $t_{PHL}$  – Propagation delay is measured from the 3.75mA level on the LOW to HIGH transition of the input current pulse to the 1.5 V level on the HIGH to LOW transition of the output voltage pulse.
- \*7.  $t_r$  – Rise time is measured from the 90% to the 10% levels on the LOW to HIGH transition of the output pulse.
- \*8.  $t_f$  – Fall time is measured from the 10% to the 90% levels on the HIGH to LOW transition of the output pulse.
- \*9.  $t_{ELH}$  – Enable input propagation delay is measured from the 1.5V level on the HIGH to LOW transition of the input voltage pulse to the 1.5V level on the LOW to HIGH transition of the output voltage pulse.
- \*10.  $t_{EHL}$  – Enable input propagation delay is measured from the 1.5V level on the LOW to HIGH transition of the input voltage pulse to the 1.5V level on the HIGH to LOW transition of the output voltage pulse.
- \*11.  $CM_H$ – The maximum tolerable rate of rise of the common mode voltage to ensure the output will remain in the HIGH state (i.e.,  $V_{OUT} > 2.0V$ ).
- \*12.  $CM_L$ – The maximum tolerable rate of rise of the common mode voltage to ensure the output will remain in the LOW output state (i.e.,  $V_{OUT} < 0.8V$ ).



## Order Information

### Part Number

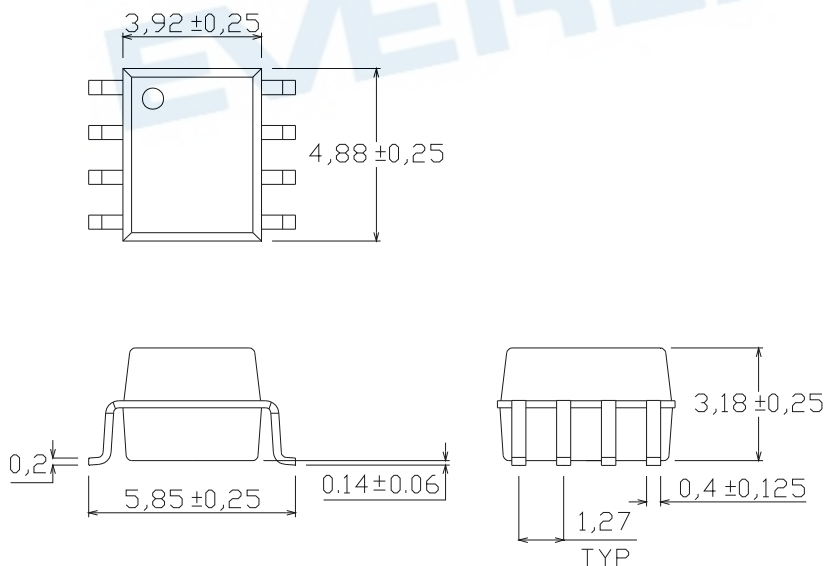
**EL06XX(Z)-V**

### Note

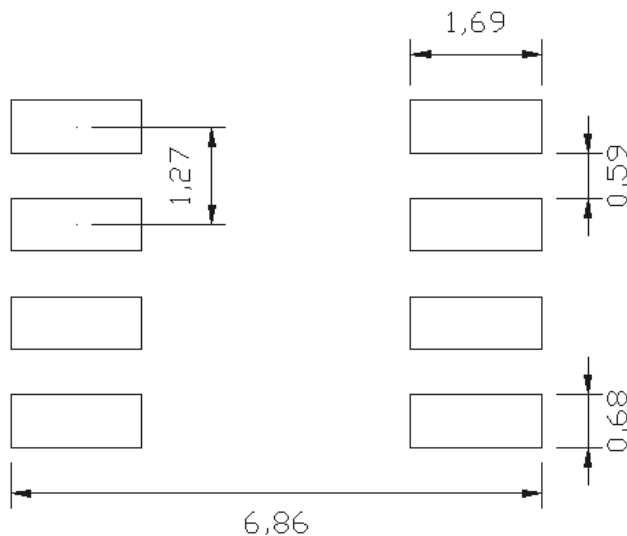
X = Part no. ( X = 00, 01 or 11)  
Z = Tape and reel option (TA, TB).  
V = VDE (optional)

Option	Description	Packing quantity
(TA)	TA tape & reel option	2000 units per reel
(TB)	TB tape & reel option	2000 units per reel
(TA)-V	TA tape & reel option + VDE	2000 units per reel
(TB)-V	TB tape & reel option + VDE	2000 units per reel

### Package Dimension (Dimensions in mm)



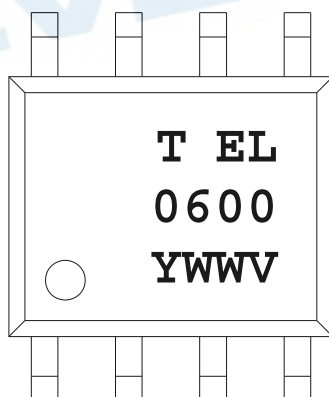
## Recommended pad layout for surface mount leadform



### Notes.

Suggested pad dimension is just for reference only.  
Please modify the pad dimension based on individual need.

## Device Marking



### Notes

T	denotes Factory No code : made in China T : made in Taiwan
EL	denotes EVERLIGHT
0600	denotes Device Number
Y	denotes 1 digit Year code
WW	denotes 2 digit Week code
V	denotes VDE (optional)

## Label form

**EVERLIGHT** 11 → 月份

客戶料號 ← CPN: XXXXXXXXXXXX 測試區

億光料號 ← P/N: XXXXXXXXXXXX

億光品名 ← EL817M(C)-VG

生產周別 ← D/C: YWWX CAT: X QTY: 000000 → 包裝數量

生產序號 ← LOT NO: Y151130XXXXXXXXXX

標籤識別碼 ← REFERENCE: BTPyyMMddXXXXX

產地 ← MADE IN XXXXXX

RoHS 標示

CEC 安規標示

QR Code

or

RoHS 標示

**EVERLIGHT** 5 → 月份

客戶料號 ← CPN: XXXXXXXXXXXX 測試區

客戶品名 ← XXXXXXXXXXXX-XXXXXXXXXX-XXXXXXXXXX-XXXXXXXXXX-XXXXXXXXXX

億光料號 ← P/N: XXXXXXXXXXXX

億光品名 ← XXXXXXXXXXXX-XXXXXXXXXX-XXXXXXXXXX-XXXXXXXXXX

生產序號 ← LOT NO: Y150516XXX-XXXXXXXXXX-XXXXXXXXXX

包裝數量 ← QTY: 0123456789 HUE: XXXXXXXXXXXX

CTR等級 ← CAT: XXXXXXXXXXXX REF: XXXXXXXXXXXX

標籤識別碼 ← REFERENCE: BTPYYMDDXXXXX

MSL等級 ← MSL-XX

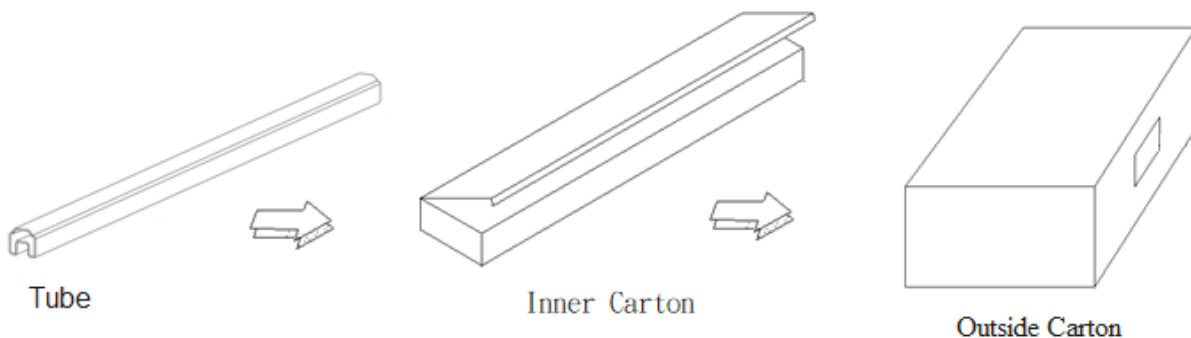
MADE IN XXXXXX

產地

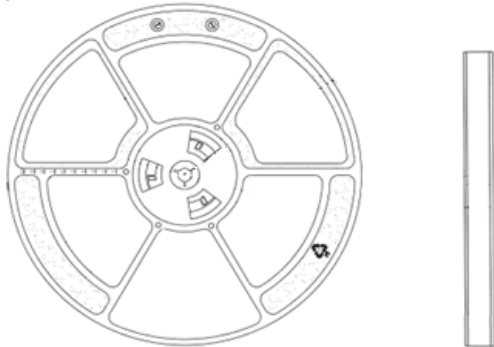
CEC 安規標示

QR Code

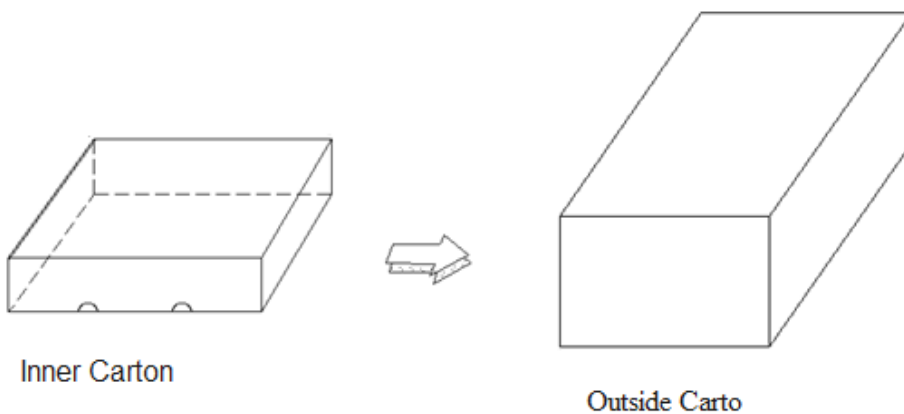
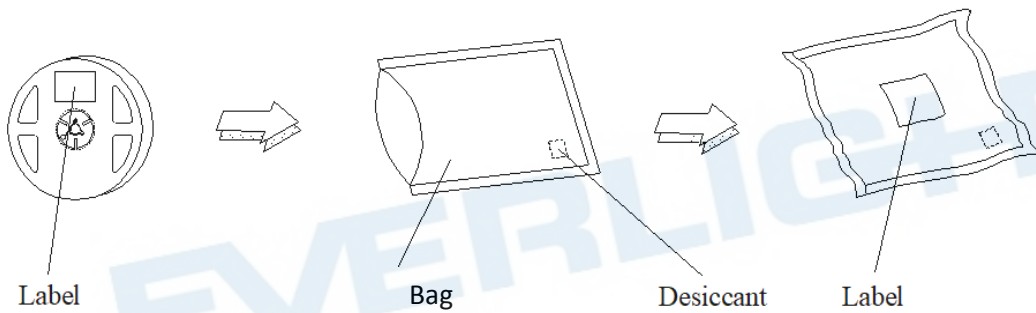
## TUBE Dimension



## Reel Dimension

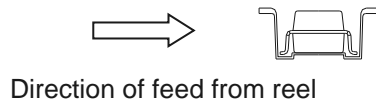
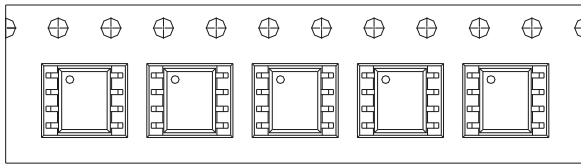


## Moisture Resistant Packaging

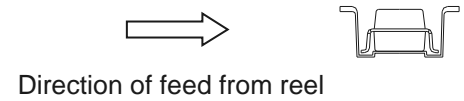
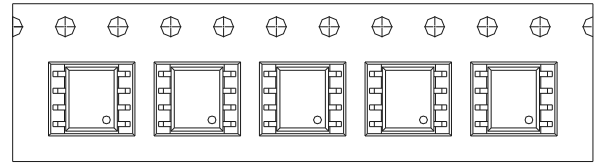


## Tape & Reel Packing Specifications

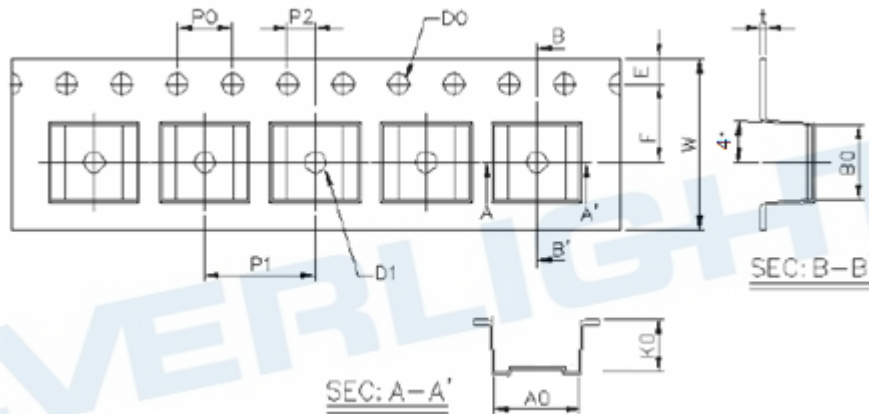
### Option TA



### Option TB



## Tape dimension

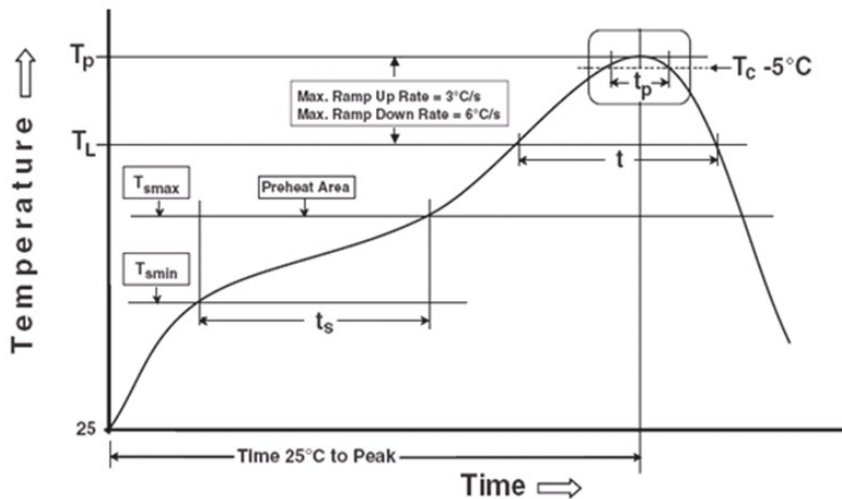


Dimension No.	A0	B0	D0	D1	E	F
Dimension(mm)	6.2±0.1	5.26±0.1	1.5±0.1	1.5±0.3	1.75±0.1	5.5±0.1
Dimension No.	Po	P1	P2	t	W	K0
Dimension(mm)	4.0±0.1	8.0±0.1	2.0±0.1	0.25±0.1	12.0+0.3/ -0.1	3.75±0.1

## Precautions for Use

### 1. Soldering Condition

#### 1.1 (A) Maximum Body Case Temperature Profile for evaluation of Reflow Profile



Note:

Reference: IPC/JEDEC J-STD-020D

#### Preheat

Temperature min ( $T_{smin}$ )	150 °C
Temperature max ( $T_{smax}$ )	200°C
Time ( $T_{smin}$ to $T_{smax}$ ) ( $t_s$ )	60-120 seconds
Average ramp-up rate ( $T_{smax}$ to $T_P$ )	3 °C/second max

#### Other

Liquidus Temperature ( $T_L$ )	217 °C
Time above Liquidus Temperature ( $t_L$ )	60-100 sec
Peak Temperature ( $T_P$ )	260°C
Time within 5 °C of Actual Peak Temperature: $T_P - 5^\circ\text{C}$	30 s
Ramp- Down Rate from Peak Temperature	6°C /second max.
Time 25°C to peak temperature	8 minutes max.
Reflow times	3 times

## Precautions for General Storage

- Avoid storage locations where devices may be exposed to moisture or direct sunlight.
- Follow the precautions printed on the packing label of the device for transportation and storage.
- Keep the storage location temperature and humidity within a range of 5°C to 35°C and 20 % to 60 %, respectively.
- Do not store the products in locations with poisonous gases (especially corrosive gases) or in dusty conditions.
- Store the products in locations with minimal temperature fluctuations. Rapid temperature changes during storage can cause condensation, resulting in lead oxidation or corrosion, which will deteriorate the solderability of the leads.
- When restoring devices after removal from their packing, use anti-static containers.
- Do not allow loads to be applied directly to devices while they are in storage.
- If devices have been stored for more than two years under normal storage conditions, it is recommended that you check the leads for ease of soldering prior to use

EVERLIGHT

## DISCLAIMER

1. Above specification may be changed without notice. EVERLIGHT will reserve authority on material change for above specification.
2. The graphs shown in this datasheet are representing typical data only and do not show guaranteed values.
3. When using this product, please observe the absolute maximum ratings and the instructions for use outlined in these specification sheets. EVERLIGHT assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.
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